

MKB4118A(P/J/E)-82/83/84

XII-47

ABSOLUTE MAXIMUM RATINGS*

Voltage on any pin relative to V_{SS} -5 V to +7.0 V
 Operating Temperature T_A (Ambient) -55°C to +125°C
 Storage Temperature (Ambient) -65°C to +150°C
 Power Dissipation 1 Watt
 Output Current 20 mA

*Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

RECOMMENDED DC OPERATING CONDITIONS⁷

(-55°C ≤ T_A ≤ +125°C)

SYM	PARAMETER	MIN	TYP	MAX	UNITS	NOTES
V_{CC}	Supply Voltage	4.75	5.0	5.25	V	1
V_{SS}	Supply Voltage	0	0	0	V	1
V_{IH}	Logic "1" Voltage All Inputs	2.4		7.0	V	1
V_{IL}	Logic "0" Voltage All Inputs	-0.3		.8	V	1, 9

DC ELECTRICAL CHARACTERISTICS^{1,7}

(-55°C ≤ T_A ≤ +125°C) (V_{CC} = +5.0 V ± 5%)

SYM	PARAMETER	MIN	MAX	UNITS	NOTES
I_{CC1}	Average V_{CC} Power Supply Current		90	mA	8
I_{CC1}	Average V_{CC} Power Supply Current T_A = 125°C		65	mA	10
I_{IL}	Input Leakage Current (Any Input)	-10	10	μA	2
I_{OL}	Output Leakage Current	-10	10	μA	2
V_{OH}	Output Logic "1" Voltage I_{OUT} = 1 mA	2.4		V	
V_{OL}	Output Logic "0" Voltage I_{OUT} = 4 mA		0.4	V	

AC ELECTRICAL CHARACTERISTICS³

(-55°C ≤ T_A ≤ 125°C) (V_{CC} = 5.0 V ± 5%)

SYM	PARAMETER	MKB4118A-82		MKB4118A-83		MKB4118A-84		UNITS	NOTES
		MIN	MAX	MIN	MAX	MIN	MAX		
t_{RC}	Read Cycle Time	150		200		250		ns	
t_{AA}	Address Access Time		150		200		250	ns	4
t_{CEA}	Chip Enable Access Time		75		100		125	ns	4
t_{CEZ}	Chip Enable Data Off Time	5	35	5	40	5	45	ns	
t_{OEA}	Output Enable Access Time		75		100		125	ns	4
t_{OEZ}	Output Enable Data Off Time	5	35	5	40	5	45	ns	
t_{AZ}	Address Data Off Time	10		10		10		ns	
t_{WC}	Write Cycle Time	150		200		250		ns	

AC ELECTRICAL CHARACTERISTICS³

(-55°C ≤ T_A ≤ +125°C) (V_{CC} = 5.0 V ± 5%)

SYM	PARAMETER	MKB4118A-82		MKB4118A-83		MKB4118A-84		UNITS	NOTES
		MIN	MAX	MIN	MAX	MIN	MAX		
t _{AS}	Address Setup Time	0		0		0		ns	see text
t _{AH}	Address Hold Time	50		65		80		ns	see text
t _{DSW}	Data To Write Setup Time	10		15		20		ns	
t _{DHW}	Data From Write Hold Time	20		25		30		ns	
t _{WD}	Write Pulse Duration	50		60		70		ns	see text
t _{WEZ}	Write Enable Data Off Time	5	35	5	40	5	45	ns	
t _{WPL}	Write Pulse Lead Time	90		130		170		ns	

CAPACITANCE^{1,7}

(-55°C ≤ T_A ≤ +125°C) (V_{CC} = +5.0 V ± 5%)

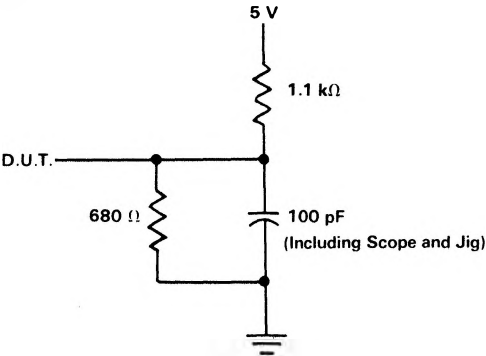
SYM	PARAMETER	TYP	MAX	NOTES
C _I	Capacitance on all pins (except D/Q)	4 pF		5
C _{D/Q}	Capacitance on D/Q pins	10 pF		5,6

NOTES:

- 1. All voltages referenced to V_{SS}.
- 2. Measured with .4 ≤ V_I 5.0 V, outputs deselected and V_{CC} = 5 V.
- 3. AC test conditions: input rise and fall times ≤ 5 ns; input levels 0 V to 3 V; timing measurement reference level 1.5 V.
- 4. Measured with a load as shown in Figure 3.
- 5. Effective capacitance calculated from the equation $C = \frac{\Delta Q}{\Delta V}$ with ΔV = 3 volts and power supplies at nominal levels.
- 6. Output buffer is deselected.
- 7. A minimum of 2 ms time delay is required after application of V_{CC} (+5 V) before proper device operation can be achieved.
- 8. I_{CC1} measured with outputs open.
- 9. Negative undershoots to a minimum of -1.5 V are allowed with maximum of 50 ns pulse width. DC value of low level must not exceed -0.3 V.
- 10. Power consumption decreases with temperature from a maximum at low temperature to a minimum at high temperature.

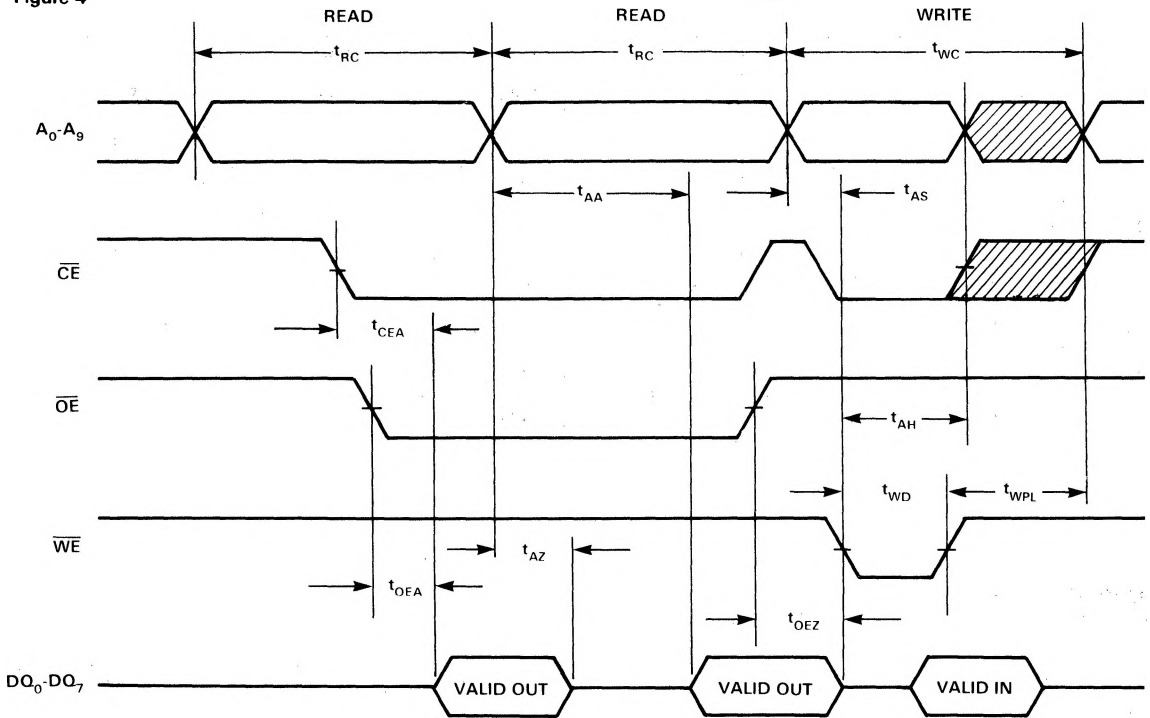
OUTPUT LOAD

Figure 3



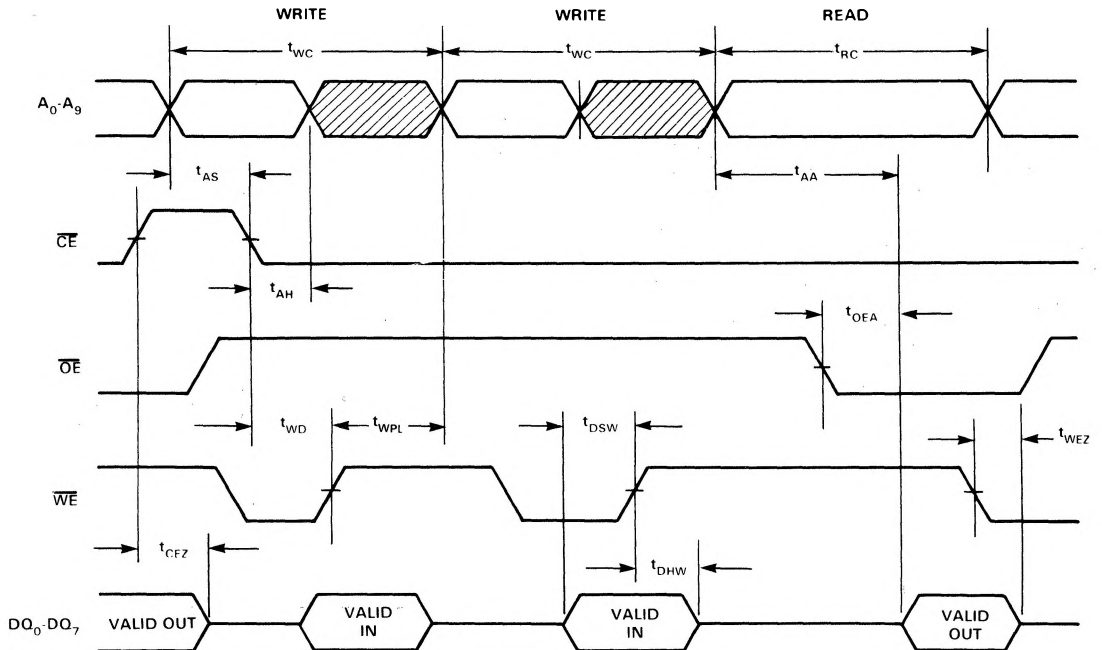
TIMING DIAGRAM

Figure 4



TIMING DIAGRAM

Figure 5



DESCRIPTION (Cont.)

The MKB4118A features a fast \overline{CE} (50% of Address Access) function to permit memory expansion without impacting system access time. A fast \overline{OE} (50% of access time) is included to permit data interleaving for enhanced system performance.

The MKB4118A is pin compatible with Mostek's BYTEWYDE™ memory family of RAMs, ROMs and EPROMs.

OPERATION

Read Mode

The MKB4118A is in the read mode whenever the Write Enable Control input (\overline{WE}) is in the high state.

In the read mode of operation, the MKB4118A provides a fast address ripple-through access of data from 8 of 8192 locations in the static storage array. Thus, the unique address specified by the 10 Address Inputs (A_n) define which 1 of 1024 bytes of data is to be accessed.

A transition on any of the 10 address inputs will disable the 8 data output drivers after t_{AZ} . Valid Data will be available to the 8 data output drivers within t_{AA} after the last address input signal is stable, providing that the \overline{CE} and \overline{OE} access times are satisfied. If \overline{CE} or \overline{OE} access times are not met, data access will be measured from the limiting parameter (t_{CEA} or t_{OEA}) rather than the address. The state of the 8 data I/O signals is controlled by the Chip Enable (\overline{CE}) and Output Enable (\overline{OE}) control signals.

Write Mode

The MKB4118A is in the write mode whenever the Write Enable (\overline{WE}) and Chip Enable (\overline{CE}) control inputs are in the low state.

The write cycle is initiated by the \overline{WE} pulse going low provided that \overline{CE} is also low. The leading edge of the \overline{WE} pulse is used to latch the status of the address bus.

NOTE: In a write cycle the latter occurring edge of either \overline{WE} or \overline{CE} will determine the start of the write cycle. Therefore, t_{AS} , t_{WD} and t_{AH} are referenced to the latter occurring edge of \overline{CE} or \overline{WE} . Addresses are latched at this time. All write cycles whether initiated by \overline{CE} or \overline{WE} must be terminated by the rising edge of \overline{WE} . If the output bus has been enabled (\overline{CE} and \overline{OE} low) then \overline{WE} will cause the output to go to the high Z state in t_{WEZ} .

Data In must be valid t_{DSW} prior to the low to high transition of \overline{WE} . The Data In lines must remain stable for t_{DHW} after \overline{WE} goes inactive. The write control of the MKB4118A disables the data out buffers during the write cycle; however, \overline{OE} should be used to disable the data out buffers to prevent bus contention between the input data and data that would be output upon completion of the write cycle.